

NOT RECOMMENDED FOR NEW DESIGN USE DZT5551

A Product Line of Diodes Incorporated



ZXTN5551G



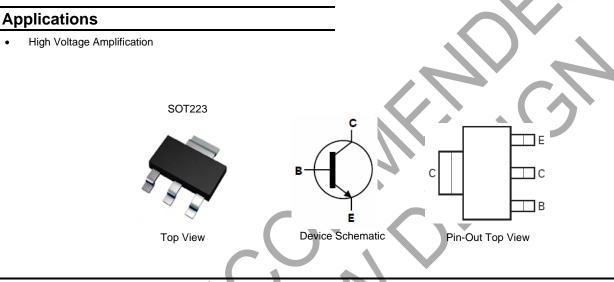
160V NPN VOLTAGE TRANSISTOR

Features

- BV_{CEO} > 160V
- BV_{EBO} > 6V
- I_C = 600mA Continuous Collector Current
- Low Saturation Voltage (150mV max @10mA)
- hFE specified up to 50mA for a high gain hold up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223
- Case material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.112 grams (Approximate)



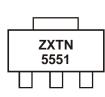
Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN5551GTA	ZXTN5551	7	12	1,000
ZXTN5551GTC	ZXTN5551	13	12	4,000

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 - 4. For packaging details, go to our website at http://www.diodes.com

Marking Information

Notes:



ZXTN5551 = Product type Marking Code





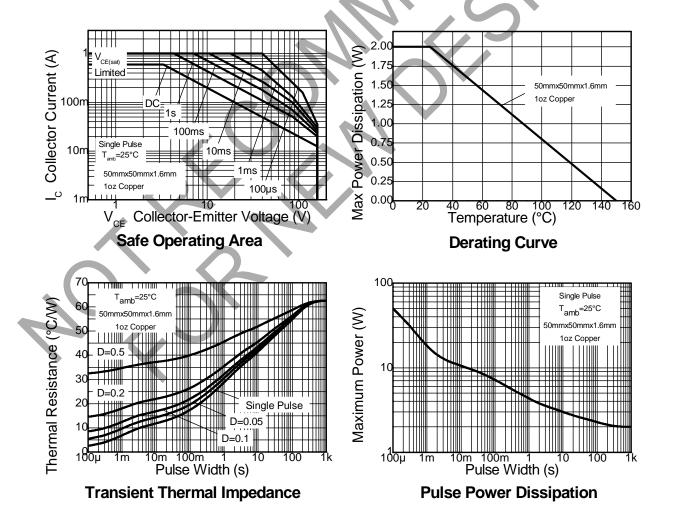
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	160	V
Emitter-Base Voltage	V _{EBO}	6	V
Continuous Collector Current	lc	600	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	2	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	62.5	°C/W
Thermal Resistance, Junction to Leads (Note 6)	R _{θJL}	34.05	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	0°

5. Device mounted on 50mm X 50mm X 1.6mm FR-4 PCB with high coverage of single sided 1 oz. copper, in still air condition Notes: 6. Thermal resistance from junction to solder-point (at the end of the collector lead).







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BVCBO	180	270	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	160	200		V	$I_{\rm C} = 1 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	7.85	—	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	_	<1 —	50 50	nΑ μΑ	V _{CB} = 120V V _{CB} = 120V, T _A = +100°C
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	65 115	150 200		$I_{C} = 10mA$, $I_{B} = 1mA$ $I_{C} = 50mA$, $I_{B} = 5mA$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	760 840	1000 1200		$I_{C} = 10$ mA, $I_{B} = 1$ mA $I_{C} = 50$ mA, $I_{B} = 5$ mA
DC Current Gain (Note 7)	h _{FE}	80 80 30	130 145 65	 250 	-	$V_{CE} = 5V, I_C = 1mA$ $V_{CE} = 5V, I_C = 10mA$ $V_{CE} = 5V, I_C = 50mA$
Transition Frequency	f _T		130	-	MHz	$V_{CE} = 10V$, $I_C = 10mA$, f = 100MHz
Small Signal	h _{FE}	50	$\langle - \rangle$	260	_ ($V_{CE} = 10V, I_C = 10mA,$ f = 1kHz
Output Capacitance (Note 7)	C _{obo}	- (\sim	6	pF	$V_{CB} = 10V$, f = 1MHz
Delay Time	t _(d)	_	95		ns	
Rise Time	t _(r)		64	—	ns	$V_{CC} = 10V, I_C = 10mA,$
Storage Time	t _(s)		1256		ns	$I_{B1} = I_{B2} = 1mA$
Delay Time	t(f)		140		ns	

Notes: 7. Pulse Test: Pulse width \leq 300µs. Duty cycle \leq 2.0%.

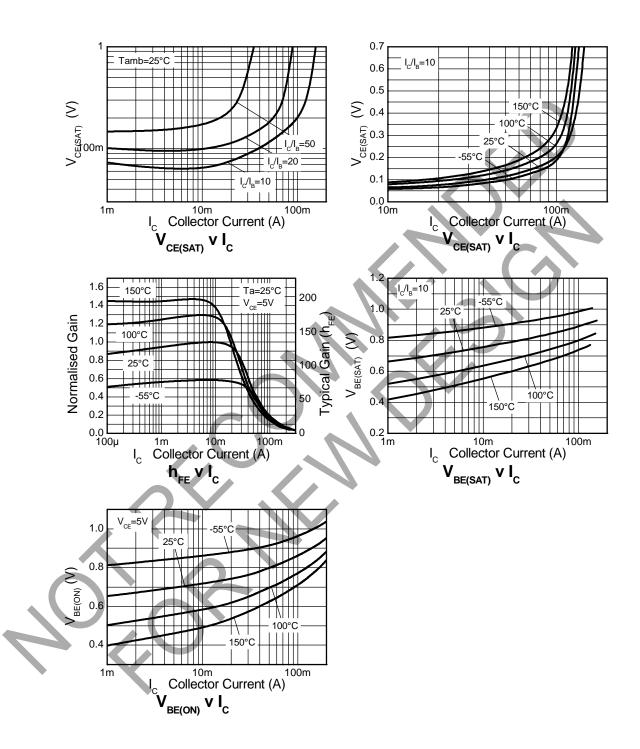


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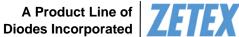
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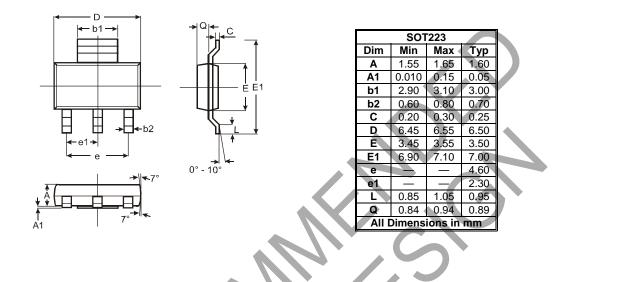






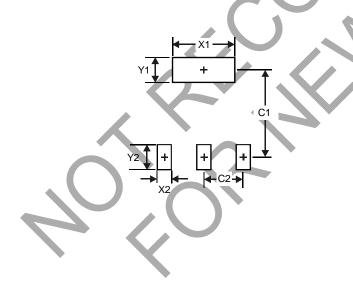
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



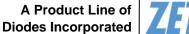
Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3







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